

DATA SHEET

**DPS-532-A**/1~5mJ

## **HIGH ENERGY DIODE** PUMPED ALL-SOLID-STATE **Q-SWITCHED LASER**

High energy diode pumped all solid state Q-switched laser at 532nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIBS, LIF, ICP-MS, LCD repair, scientific research, and so on.











## **SPECIFICATIONS**

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Wavelength (nm)	532±1	
Operating mode	Q-switched:EOM(Electro-optic Modulation)	Q-switched: PM (Passive Modulation)
Single pulse energy (mJ)	5	
Pulse duration (ns)	<10	
Rep. rate (Hz)	1~10, EXT (adjustable)	
Energy stability (rms)	<5%,<3%	<5%
Beam divergence, full angle (mrad)	<3	
Beam diameter (mm)	~3	
Warm-up time (minutes)	<15	
Beam height from base plate (mm)	37	
Cooled method	Conduction cooled	
Operating temperature (°C)	15~30	
Power supply (220V AC/24V DC)	PSU-DPS-A	
Expected lifetime (pulses)	10 9	
Warranty period	1 year	
Available options	Jitter (Sdev):~1ns ( Electro-optic modulation) ; Battery power supply	





